Vishay Siliconix

1.6 Ω On Resistance, \pm 5 V, \pm 12 V, and \pm 3 V Quad SPST Switches

DESCRIPTION

The DG9424E, DG9425E, DG9426E are monolithic quad single-pole-single-throw analog switches. The G9424E and DG9425E differ only in that they respond to opposite logic levels. The DG9426E has two normally open and two normally closed switches. It can be given various configurations, including four SPST, two SPDT, and one DPDT.

Using BiCMOS wafer fabrication technology allows the DG9424E, DG9425E, and DG9426E to operate on single and dual supplies. Single supply voltage ranges from 3 V to 16 V while dual supply operation is recommended with \pm 3 V to \pm 8 V. Each switch conducts equally well in both direction when on, and blocks input voltages up to the supply levels when off.

The low and flat on resistance over the full input signal voltage rang bring excellent linearity, reduce insertion loss and signal distortion, make them ideal for data acquisition and programmable gain control applications. These switch characters also make them ideal fit for audio signal switch and reed relay replacement.

The DG9424E, DG9425E, DG9426E feature low power dissipation, fast switching speed, and low voltage logic control threshold. Proprietary design enables the low charge injection that minimize the switching transient.

Operation temperature is specified from -40 °C to +85 °C. The DG9424E, DG9425E, DG9426E are available in 16 lead TSSOP packages.

FEATURES

- 3 V to 16 V single supply or ± 3 V thru ± 8 V dual supply operation
- 1.6 Ω typical on resistance
- 3 V logic compatible for control
- · Bidirectional rail to rail signal switching
- · Fast switching speed
- < 0.2 nA switch on leakage
- Break-before-make switching DG9426

BENEFITS

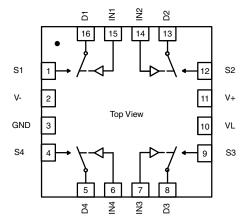
- Wide operation voltage range
- · Low signal errors and distortion
- · Fast switching time
- Simple interfacing

APPLICATIONS

- · Automatic test equipment
- · Data acquisition systems
- Meters and instruments
- Medical and healthcare systems
- Communication systems
- Audio and video signal routing
- Relay replacement
- Battery powered systems
- Computer peripherals
- Audio and video signal routing

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

QFN-16 (4 mm x 4 mm)

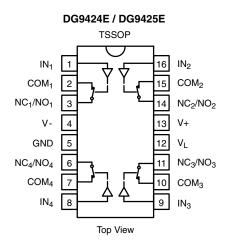


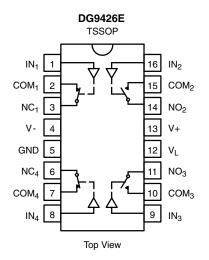
Note

• QFN exposed pad can either be tied to V- or left floating

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FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION





TRUTH TABLE								
LOGIC	DG9424E	DG9425E						
0	Off	On						
1	On	Off						

TRUTH TABLE									
LOGIC	SW ₁ , SW ₄	SW ₂ , SW ₃							
0	On	Off							
1	Off	On							

ORDERING INFORMATION										
TEMP. RANGE	PACKAGE	PART NUMBER	PART MARKING	STD PACK QUANTITY						
		DG9424EDQ-T1-GE3	9424E	Tape and reel 3000 units						
	16-pin TSSOP	DG9425EDQ-T1-GE3	9425E	Tape and reel 3000 units						
-40 °C to +85 °C		DG9426EDQ-T1-GE3	9426E	Tape and reel 3000 units						
-40 C t0 +65 C	0.511/4	DG9424EDN-T1-GE4	9424E	Tape and reel 2500 units						
	QFN (4 mm x 4 mm) 16L (variation 2)	DG9425EDN-T1-GE4	9425E	Tape and reel 2500 units						
		DG9426EDN-T1-GE4	9426E	Tape and reel 2500 units						

ABSOLUTE MAXIMUM RATINGS									
PARAMETER		LIMIT	UNIT						
V+ to V-		-0.3 to +18							
GND to V-		18	V						
V _L		(GND - 0.3) to (V+) + 0.3	V						
IN, COM, NC, NO a		(V-) - 0.3 to (V+) + 0.3							
Continuous current (NO, NC, COM pi	ns)	100	··· Λ						
Peak current, S or D (pulsed 1 ms, 10	% duty cycle)	200	mA						
Storage temperature		-65 to +150	°C						
Power dissipation (package) b	16 nin T000D 0	450	mW						
Thermal resistance b 16-pin TSSOP c		178	°C/W						
ESD human body model (HBM); per A	NSI / ESDA / JEDEC® JS-001	>1500	V						
Latch up current, per JESD78D		400	mA						

Notes

- a. Signals on NC, NO, COM or IN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings
- b. All leads welded or soldered to PC board
- c. Derate 7 mW/°C above 25 °C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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SPECIFICATIONS a Sing	le Supply 1	2 V					
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED		-40	5 °C	UNIT	
		V+ = 12 V, V- = 0 V $V_L = 5 V, V_{IN} = 2.4 V, 0.8 V f$		MIN. d	TYP. c	MAX. d	
Analog Switch					ı	,	L
Analog signal range ^e	V _{ANALOG}		Full	0	-	12	V
On-resistance	R _{ON}	V+ = 10.8 V, V- = 0 V, $I_{NO}, I_{NC} = 50 \text{ mA}, V_{COM} = 2/9 \text{ V}$	Room	-	1.6	3 4	Ω
Digital Control							<u> </u>
Input current	I _{INL} or I _{INH}		Full	-1	0.01	1	μA
Dynamic Characteristics					L	L	
T 9			Room	-	36	51	
Turn-on time ^e	t _{ON}	$R_1 = 300 \Omega, C_1 = 35 pF,$	Full	-	-	65	
Turn-off time e	t _{OFF}	V_{NO} , $V_{NC} = 5$ V, see Fig. 2	Room	-	20	35	ns
rum-on time •			Full	-	-	44	
Break-before-make time delay e	t _D	DG9426E only, V_{NO} , V_{NC} = 5 V, R_L = 300 Ω , C_L = 35 pF	Room	2	-	-	
Charge injection ^e	Q _{INJ}	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room	-	38	-	рС
Off-isolation ^e	OIRR	$R_L = 50 \Omega$, $C_L = 5 pF$,	Room	-	-56	-	dB
Channel-to-channel crosstalk e	X _{TALK}	f = 1 MHz	Room	-	-77	-	иь
NO, NC off capacitance e	C _{NO(off)}		Boom	-	49	_	
NO, NO on capacitance	C _{NC(off)}	f = 1 MHz	Room	-	49	_	pF
COM off capacitance e	C _{COM(off)}	I = I IVIDZ	Room	ı	37	-	ρг
Channel on capacitance ^e	C _{COM(on)}		Room	ı	89	-	
Power Supplies							
Positive supply current	l+		Room	ı	0.02	1	
1 Ositive supply current	IT		Full	-	-	5	
Negative supply current	l-		Room	-1	-0.002	-	
regative supply current	I-	$V_{IN} = 0$ or V_{L}	Full	-5	-	-	μΑ
Logic supply current	Ι _L	AIN - O OI AF	Room	-	0.002	1	μΛ
Logio dappiy darront	'L		Full	-	-	5	
Ground current	laus		Room	-1	-0.002	-	
Ground Guiront	I _{GND}		Full	-5	-	-	



Vishay Siliconix

PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED		LIMITS -40 °C to +85 °C			UNIT
		V+ = 5 V, V- = 5 V $V_L = 5 V, V_{IN} = 2.4 V, 0.8 V f$		MIN. d	TYP. c	MAX. d	
Analog Switch							
Analog signal range ^e	V _{ANALOG}		Full	-5		5	V
On-resistance	R _{ON}	V+ = 4.5 V, V- = -4.5 V, $I_{NO}, I_{NC} = 50 \text{ mA}$	Room Full	-	1.9	3.3 4.3	Ω
	I _{NO(off)}		Room	-1	-	1	
O Mahamilaalaa aa aa aa	I _{NC(off)}	V+ = 5.5 V, V- = -5.5 V,	Full	-10	-	10	
Switch off leakage current		$V_{COM} = \pm 4.5 \text{ V}, V_{NO}, V_{NC} = \pm 4.5 \text{ V}$	Room	-1	-	1	
	I _{COM(off)}		Full	-10	-	10	nA
Channel an lankana arment		V+ = 5.5 V, V- = -5.5 V,	Room	-1	-	1	
Channel on leakage current	ICOM(on)	V_{NO} , $V_{NC} = V_{COM} = \pm 4.5 \text{ V}$	Full	-10	-	10	
Digital Control							
Input current ^a	I _{INL} or I _{INH}		Full	-1	0.05	1	μA
Dynamic Characteristics	<u> </u>						
Turn-on time ^e		$R_L = 300 \ \Omega, \ C_L = 35 \ pF,$	Room	-	48	67	-
rum-on time s	t _{ON}		Full	-	-	81	
Turn-off time e		V_{NO} , $V_{NC} = \pm 3.5 \text{ V}$, see Fig. 2		-	34	57	ns
Turri-on time s	t _{OFF}		Full	-	-	67] '''
Break-before-make time delay e	t _D	DG9426E only, V_{NO} , V_{NC} = 3.5 V, R_L = 300 Ω , C_L = 35 pF	Room	2	-	-	
Charge injection ^e	Q _{INJ}	V_g = 0 V, R_g = 0 Ω , C_L = 1 nF	Room	-	112	-	рC
Off isolation e	OIRR	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$	Room	-	-56	-	dE
Channel-to-channel crosstalk e	X _{TALK}	$H_L = 30.52, G_L = 5 \text{ pr}, T = T \text{ MHz}$	Room	-	-82	-	UL
Source off capacitance e	C _{NO(off)} C _{NC(off)}		Room	ı	38	1	
Drain off capacitance e	C _{COM(off)}	f = 1 MHz	Room	-	38	-	рF
Channel on capacitance e	C _{COM(on)}		Room	-	89	-	
Power Supplies							
Positive supply current ^e	l+		Room	-	0.03	1	
Tositive supply current	1+		Full	-	-	5	
Negative supply current e	 -		Room	-1	-0.002	-	
rvegative supply current		$V_{IN} = 0$ or V_{I}	Full	-5	-	-	
Logio supply current 6	1.	VIN = O Or VL	Room	-	0.002	1	μA
Logic supply current ^e	IL		Full	-	-	5	
Crown decrease 6	,		Room	-1	-0.002	-	
Ground current e	I _{GND}		Full	-5	-	-	



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SPECIFICATIONS a Singl	e Supply 5	v					
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP.b	-40	LIMITS °C to +8	5 °C	UNIT
		V+ = 5 V, V- = 0 V $V_L = 5 V, V_{IN} = 2.4 V, 0.8 V^f$		MIN. d	TYP. c	MAX. d	
Analog Switch							
Analog signal range ^e	V _{ANALOG}		Full	-	=	5	V
On-resistance e	R _{ON}	$V_{+} = 4.5 \text{ V}, I_{NO}, I_{NC} = 50 \text{ mA}$	Room	-	3.1	4.8	Ω
On-resistance	LON	V+ = 4.5 V, I _{NO} , I _{NC} = 50 IIIA	Full	-	-	5.8	22
Dynamic Characteristics							
Turn-on time e	tou		Room	-	62	78	
rum-on time -	t _{ON}	$R_L = 300 \Omega, C_L = 35 pF,$	Hot	-	-	106	
Turn-off time e	t _{OFF}	V _{NO} , V _{NC} = 3.5 V, see Fig. 2		-	29	44	ns
Turn-on time 5			Hot	-	-	56	110
Break-before-make time delay ^e	t _D	DG9426E only, V_{NO} , V_{NC} = 3.5 V, R_L = 300 Ω , C_L = 35 pF	Room	5	-	-	
Charge injection ^e	Q _{INJ}	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room	-	10	-	рС
Power Supplies							
Positive supply current e	l+		Room	-	0.02	1	
Positive supply current •	I+		Hot	-	-	5	
Negative events everent 6	I-		Room	-1	-0.002	-	
Negative supply current e	I-	V 0 0 0 V	Hot	-5	-	-	
Logic supply current 6	I.	$V_{IN} = 0$ or V_L	Room	-	0.002	1	μΑ
Logic supply current ^e	IL		Hot	-	=	5	
Ground current e	1		Room	-1	-0.002	-	
Glouila culterit	I _{GND}		Hot	-5	-	-	



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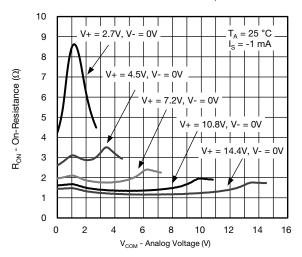
SPECIFICATIONS a Single Supply 3 V										
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED		LIMITS -40 °C to +85 °C			UNIT			
	01111202	V+ = 3 V, V- = 0 V $V_L = 3 V, V_{IN} = 2.4 V, 0.4 V^f$		MIN. d	TYP. c	MAX. d				
Analog Switch										
Analog signal range ^e	V _{ANALOG}		Full	0	-	3	V			
On-resistance	R_{ON}	V+ = 2.7 V, V- = 0 V.	Room	-	6	-	Ω			
On resistance	TION	I_{NO} , $I_{NC} = 5$ mA, $V_{COM} = 0.5$, 2.2 V	Full	-	-	-	32			
	I _{NO(off)}		Room	-1	-	1				
Switch off leakage current a	I _{NC(off)}	V+ = 3.3 V, V- = 0 V.	Full	-10	-	10				
Switch on leakage current	laasse sa	$V_{COM} = 0.3, 3 \text{ V}, V_{NO}, V_{NC} = 3, 0.3 \text{ V}$	Room	-1	-	1	nA			
	I _{COM(off)}		Full	-10	-	10	11/4			
Channel on leakage current a	laa	V+ = 3.3 V, V- = 0 V,	Room	-1	-	1				
Charmer on leakage current -	I _{COM(on)}	$V_{NO}, V_{NC} = V_{COM} = 0.3, 3 \text{ V}$	Full	-10	-	10				
Digital Control ^e										
Input current	I _{INL} or I _{INH}		Full	-1	0.005	1	μΑ			
Dynamic Characteristics										
Turn-on time	t _{ON}		Room	-	170	-				
Turn on time	ON	$R_L = 300 \Omega$, $C_L = 35 pF$.	Full	-	-	230				
Turn-off time	t _{OFF}	V_{NO} , $V_{NC} = 1.5 V$, see Fig. 2	Room	-	65	-	ns			
Turn-on time	LOFF		Full	-	-	89				
Break-before-make time delay	t _D	DG9426E only, V_{NO} , V_{NC} = 1.5 V, R_L = 300 Ω , C_L = 35 pF	Room	5						
Charge injection ^e	Q_{INJ}	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room	-	15	-	рС			
Off isolation ^e	OIRR	$R_L = 50 \Omega, C_L = 5 pF,$	Room	-	-56	-	dB			
Channel-to-channel crosstalk e	X _{TALK}	f = 1 MHz	Room	=	-80	-	аь			
Source off capacitance e	C _{NO(off)}		Room	_	53	_				
Source on Capacitance	C _{NC(off)}	f = 1 MHz	nooiii		33		pF			
Drain off capacitance e	C _{COM(off)}	I = I IVICIZ	Room	-	42	-	pΓ			
Channel on capacitance e	C _{COM(on)}		Room	-	92	-				

Notes

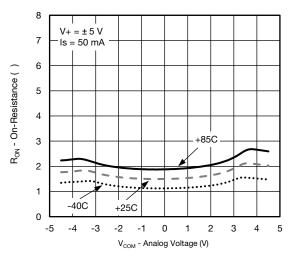
- a. Leakage parameters are guaranteed by worst case test conditions and not subject to production test
- b. Room = 25 $^{\circ}$ C, Full = As determined by the operating temperature suffix
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet
- e. Guaranteed by design, not subject to production test
- f. V_{IN} = Input voltage to perform proper function

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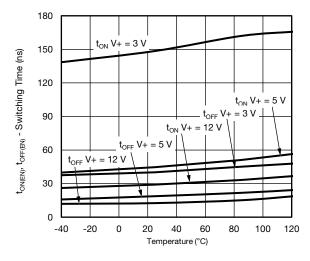
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



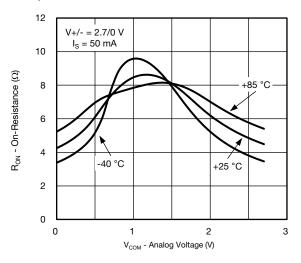
R_{ON} vs. V_{COM} and Supply Voltage



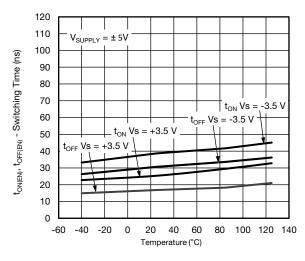
R_{ON} vs. Analog Voltage and Temperature



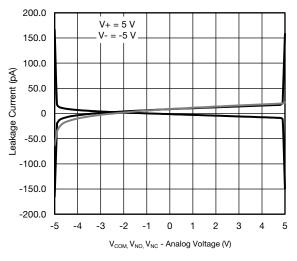
Switching Time vs. Temperature and Single Supply Voltage



R_{ON} vs. Analog Voltage and Temperature



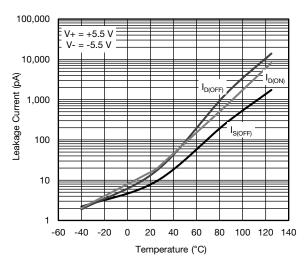
Switching Time vs. Temperature and Dual Supply Voltage



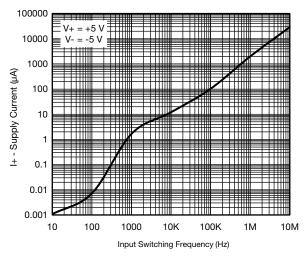
Leakage Current vs. Analog Voltage

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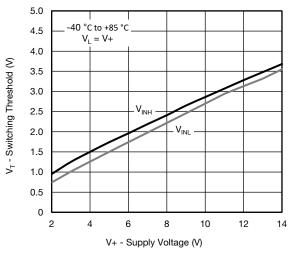
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



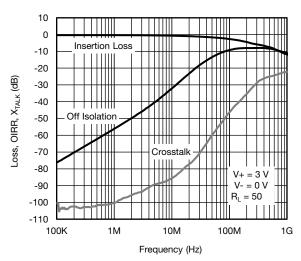
Leakage Current vs. Temperature



Switching Current vs. Input Switching Frequency



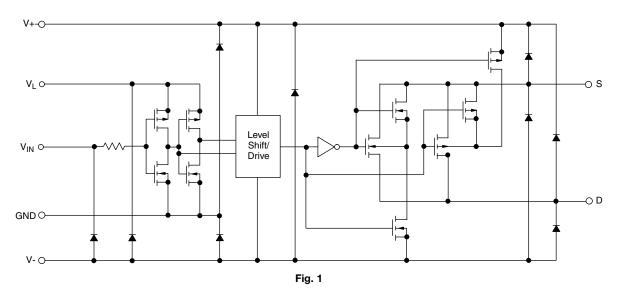
Switching Threshold vs. Supply Voltage



Insertion Loss, Off Isolation and Crosstalk vs. Frequency

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SCHEMATIC DIAGRAM (typical channel)



TEST CIRCUITS

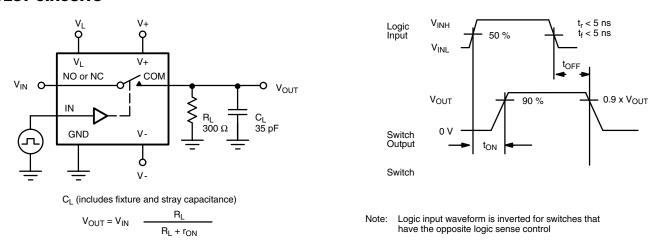


Fig. 2 - Switching Time

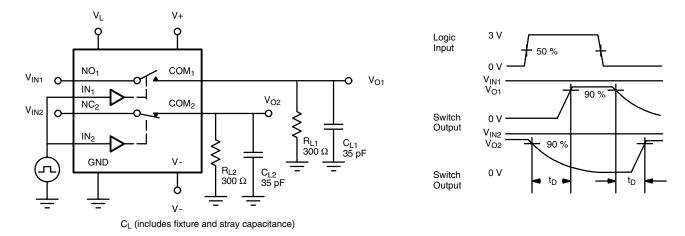
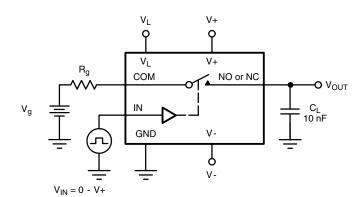
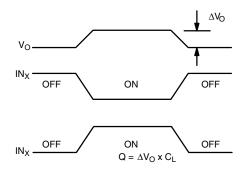


Fig. 3 - Break-Before-Make (DG9426E)

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TEST CIRCUITS





 $\ensuremath{\mathsf{IN}}_X$ dependent on switch configuration Input polarity determined by sense of switch.

Fig. 4 - Charge Injection

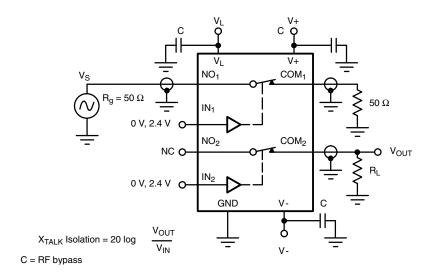


Fig. 5 - Crosstalk

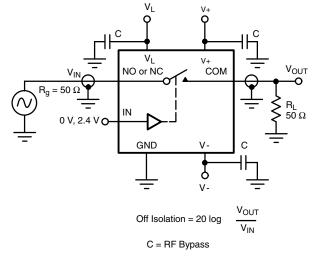


Fig. 6 - Off-Isolation

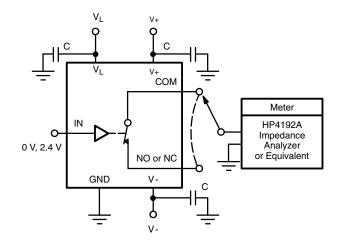


Fig. 7 - Source/Drain Capacitances



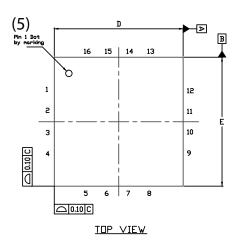
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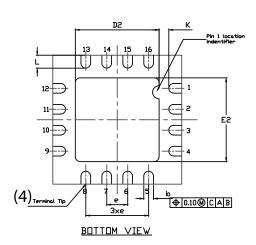
PRODUCT SUMM	MARY					
Part number	DG9424E	DG9424E	DG9425E	DG9425E	DG9426E	DG9426E
Status code	2	2	2	2	2	2
Configuration	SPST x 4, NO	SPST x 4, NO	SPST x 4, NC	SPST x 4, NC	SPST x 4, comp	SPST x 4, comp
Single supply min. (V)	3	3	3	3	3	3
Single supply max. (V)	16	16	16	16	16	16
Dual supply min. (V)	3	3	3	3	3	3
Dual supply max. (V)	8	8	8	8	8	8
On-resistance (Ω)	1.6	1.6	1.6	1.6	1.6	1.6
Charge injection (pC)	38	38	38	38	38	38
Source on capacitance (pF)	89	89	89	89	89	89
Source off capacitance (pF)	37	37	37	37	37	37
Leakage switch on typ. (nA)	-	-	-	-	-	-
Leakage switch off max. (nA)	1	1	1	1	1	1
-3 dB bandwidth (MHz)	-	-	-	-	-	-
Package	TSSOP-16	QFN-16 4 x 4	TSSOP-16	QFN-16 4 x 4	TSSOP-16	QFN-16 4 x 4
Functional circuit / applications	Multi purpose, instrumentation, medical and healthcare, portable					
Interface	Parallel	Parallel	Parallel	Parallel	Parallel	Parallel
Single supply operation	Yes	Yes	Yes	Yes	Yes	Yes
Dual supply operation	Yes	Yes	Yes	Yes	Yes	Yes
Turn on time max. (ns)	51	51	51	51	51	51
Crosstalk and off isolation	-56	-56	-56	-56	-56	-56

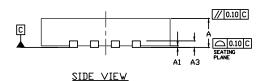
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?75770.



QFN 4x4-16L Case Outline







		VARIATION 1						VARIATION 2				
DIM	МІ	MILLIMETERS(1)			INCHES		MILLIMETERS(1)			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
Α	0.75	0.85	0.95	0.029	0.033	0.037	0.75	0.85	0.95	0.029	0.033	0.037
A1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002
A3		0.20 ref.			0.008 ref.			0.20 ref.			0.008 ref.	
b	0.25	0.30	0.35	0.010	0.012	0.014	0.25	0.30	0.35	0.010	0.012	0.014
D	4.00 BSC)	0.157 BSC		4.00 BSC			0.157 BSC			
D2	2.0	2.1	2.2	0.079	0.083	0.087	2.5	2.6	2.7	0.098	0.102	0.106
е		0.65 BS0			0.026 BSC			0.65 BSC			0.026 BSC	
Е		4.00 BS0			0.157 BSC			4.00 BSC			0.157 BSC	
E2	2.0	2.1	2.2	0.079	0.083	0.087	2.5	2.6	2.7	0.098	0.102	0.106
K		0.20 min.			0.008 min.			0.20 min.			0.008 min.	
L	0.5	0.6	0.7	0.020	0.024	0.028	0.3	0.4	0.5	0.012	0.016	0.020
N ⁽³⁾	16		3		16		16			16		
Nd ⁽³⁾		4			4		4			4		
Ne ⁽³⁾		4		4 4 4			4					

Notes

- (1) Use millimeters as the primary measurement.
- (2) Dimensioning and tolerances conform to ASME Y14.5M. 1994.
- (3) N is the number of terminals. Nd and Ne is the number of terminals in each D and E site respectively.
- (4) Dimensions b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip.
- (5) The pin 1 identifier must be existed on the top surface of the package by using identification mark or other feature of package body.
- (6) Package warpage max. 0.05 mm.

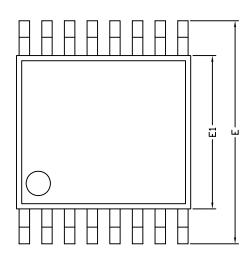
ECN: S13-0893-Rev. B, 22-Apr-13

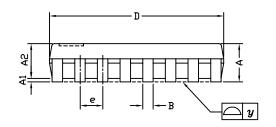
DWG: 5890

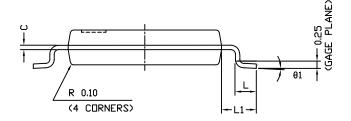
Revision: 22-Apr-13



TSSOP: 16-LEAD







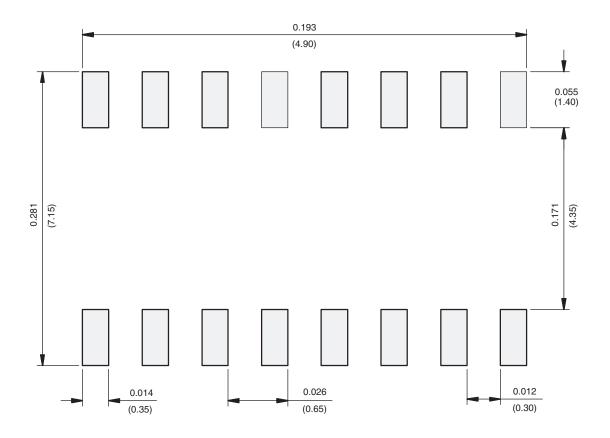
	DIMENSIONS IN MILLIMETERS							
Symbols	Min	Nom	Max					
А	=	1.10	1.20					
A1	0.05	0.10	0.15					
A2	=	1.00	1.05					
В	0.22	0.28	0.38					
С	=	0.127	-					
D	4.90	5.00	5.10					
E	6.10	6.40	6.70					
E1	4.30	4.40	4.50					
е	-	0.65	-					
L	0.50	0.60	0.70					
L1	0.90	1.00	1.10					
у	=	-	0.10					
θ1	0°	3°	6°					
ECN: S-61920-Rev. D. 23-0	Oct-06	<u> </u>						

DWG: 5624

Document Number: 74417 www.vishay.com 23-Oct-06



RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads Dimensions in inches (mm)



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